

## Standard Rectifier

| 1~<br>Rectifier |          |
|-----------------|----------|
| $V_{RRM}$       | = 1200 V |
| $I_{DAV}$       | = 40 A   |
| $I_{FSM}$       | = 320 A  |

### 1~ Rectifier Bridge

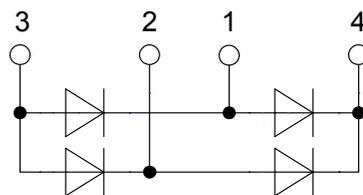
Part number

VBO40-12NO6



Backside: isolated

 E72873



#### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

#### Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

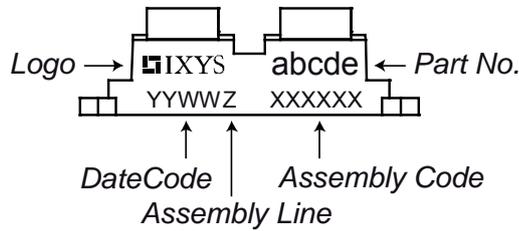
#### Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

| Rectifier  |  |  |   | Ratings                  |      |      |                  |
|------------|--|--|---|--------------------------|------|------|------------------|
| Symbol     | Definition                                   | Conditions                               |   | min.                     | typ. | max. | Unit             |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage |  |   |                          |      | 1300 | V                |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     |  |   |                          |      | 1200 | V                |
| $I_R$      | reverse current                              | $V_R = 1200$ V                           | $T_{VJ} = 25^\circ\text{C}$             |                          |      | 40   | $\mu\text{A}$    |
|            |  | $V_R = 1200$ V                           | $T_{VJ} = 150^\circ\text{C}$            |                          |      | 1.5  | mA               |
| $V_F$      | forward voltage drop                         | $I_F = 20$ A                             | $T_{VJ} = 25^\circ\text{C}$             |                          |      | 1.15 | V                |
|            |  | $I_F = 40$ A                             |   |                          |      | 1.33 | V                |
|            |  | $I_F = 20$ A                             | $T_{VJ} = 125^\circ\text{C}$            |                          |      | 1.07 | V                |
|            |  | $I_F = 40$ A                             |   |                          |      | 1.31 | V                |
| $I_{DAV}$  | bridge output current                        | $T_C = 115^\circ\text{C}$<br>rectangular | $T_{VJ} = 150^\circ\text{C}$<br>d = 0.5 |                          |      | 40   | A                |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only        |   |                          |      | 0.81 | V                |
| $r_F$      | slope resistance                             |  |   |                          |      | 12.1 | m $\Omega$       |
| $R_{thJC}$ | thermal resistance junction to case          |  |   |                          |      | 1.3  | K/W              |
| $R_{thCH}$ | thermal resistance case to heatsink          |  |   |                          | 0.10 |      | K/W              |
| $P_{tot}$  | total power dissipation                      |  |   | $T_C = 25^\circ\text{C}$ |      | 95   | W                |
| $I_{FSM}$  | max. forward surge current                   | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 45^\circ\text{C}$             |                          |      | 320  | A                |
|            |  | t = 8,3 ms; (60 Hz), sine                | $V_R = 0$ V                             |                          |      | 345  | A                |
|            |  | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 150^\circ\text{C}$            |                          |      | 270  | A                |
|            |  | t = 8,3 ms; (60 Hz), sine                | $V_R = 0$ V                             |                          |      | 295  | A                |
| $I^2t$     | value for fusing                             | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 45^\circ\text{C}$             |                          |      | 510  | A <sup>2</sup> s |
|            |  | t = 8,3 ms; (60 Hz), sine                | $V_R = 0$ V                             |                          |      | 495  | A <sup>2</sup> s |
|            |  | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 150^\circ\text{C}$            |                          |      | 365  | A <sup>2</sup> s |
|            |  | t = 8,3 ms; (60 Hz), sine                | $V_R = 0$ V                             |                          |      | 360  | A <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400$ V; f = 1 MHz                 | $T_{VJ} = 25^\circ\text{C}$             |                          | 11   |      | pF               |

| Package SOT-227B (minibloc) |  |                      |                                     | Ratings |      |      |
|-----------------------------|--|----------------------|-------------------------------------|---------|------|------|
| Symbol                      | Definition   | Conditions           | min.                                | typ.    | max. | Unit |
| $I_{RMS}$                   | RMS current  | per terminal         |                                     |         | 150  | A    |
| $T_{stg}$                   | storage temperature  |                      | -40                                 |         | 150  | °C   |
| $T_{VJ}$                    | virtual junction temperature                                 |                      | -40                                 |         | 150  | °C   |
| <b>Weight</b>               |  |                      |                                     | 30      |      | g    |
| $M_D$                       | mounting torque  |                      | 1.1                                 |         | 1.5  | Nm   |
| $M_T$                       | terminal torque  |                      | 1.1                                 |         | 1.5  | Nm   |
| $d_{Spp/App}$               | creepage distance on surface   striking distance through air | terminal to terminal | 10.5                                | 3.2     |      | mm   |
| $d_{Spt/Abp}$               |  | terminal to backside | 8.6                                 | 6.8     |      | mm   |
| $V_{ISOL}$                  | isolation voltage  | t = 1 second         |                                     | 3000    |      | V    |
|                             |  | t = 1 minute         | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 2500    |      | V    |

### Product Marking



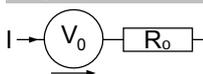
| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | VBO40-12NO6 | VBO40-12NO6        | Tube          | 10       | 475890   |

| Similar Part | Package             | Voltage class |
|--------------|---------------------|---------------|
| VBO40-16NO6  | SOT-227B (minibloc) | 1600          |
| VBO40-08NO6  | SOT-227B (minibloc) | 800           |

### Equivalent Circuits for Simulation

\* on die level

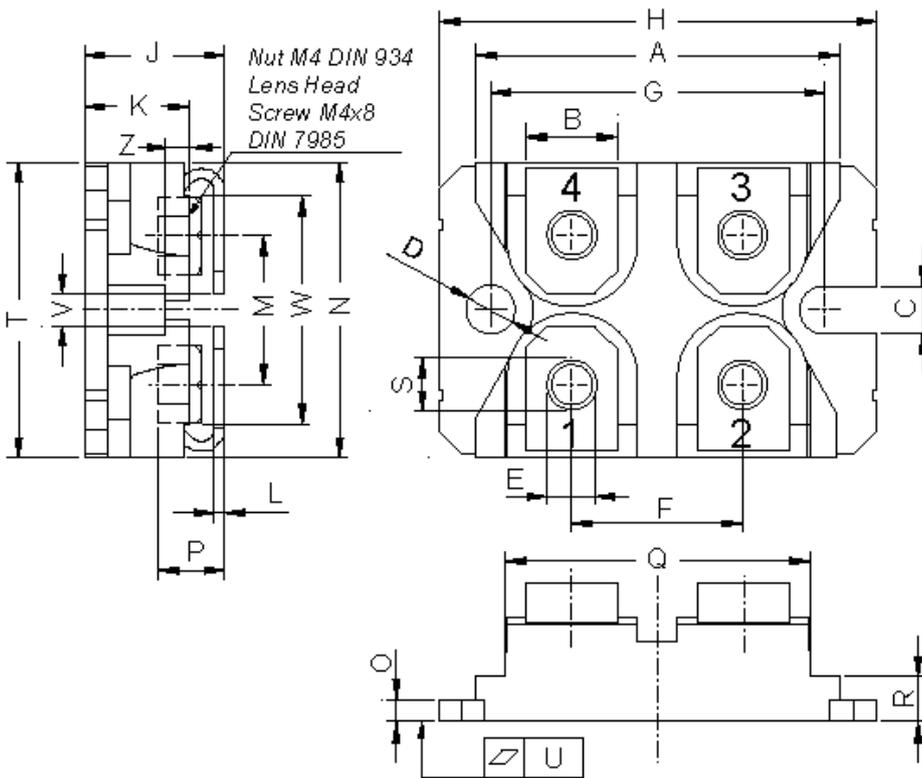
$T_{VJ} = 150\text{ °C}$



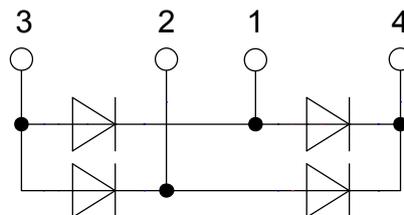
Rectifier

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0.81 | V  |
| $R_{0\ max}$ | slope resistance * | 10.2 | mΩ |

## Outlines SOT-227B (minibloc)



| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | min        | max   | min    | max   |
| A    | 31.50      | 31.88 | 1.240  | 1.255 |
| B    | 7.80       | 8.20  | 0.307  | 0.323 |
| C    | 4.09       | 4.29  | 0.161  | 0.169 |
| D    | 4.09       | 4.29  | 0.161  | 0.169 |
| E    | 4.09       | 4.29  | 0.161  | 0.169 |
| F    | 14.91      | 15.11 | 0.587  | 0.595 |
| G    | 30.12      | 30.30 | 1.186  | 1.193 |
| H    | 37.80      | 38.23 | 1.488  | 1.505 |
| J    | 11.68      | 12.22 | 0.460  | 0.481 |
| K    | 8.92       | 9.60  | 0.351  | 0.378 |
| L    | 0.74       | 0.84  | 0.029  | 0.033 |
| M    | 12.50      | 13.10 | 0.492  | 0.516 |
| N    | 25.15      | 25.42 | 0.990  | 1.001 |
| O    | 1.95       | 2.13  | 0.077  | 0.084 |
| P    | 4.95       | 6.20  | 0.195  | 0.244 |
| Q    | 26.54      | 26.90 | 1.045  | 1.059 |
| R    | 3.94       | 4.42  | 0.155  | 0.167 |
| S    | 4.55       | 4.85  | 0.179  | 0.191 |
| T    | 24.59      | 25.25 | 0.968  | 0.994 |
| U    | -0.05      | 0.10  | -0.002 | 0.004 |
| V    | 3.20       | 5.50  | 0.126  | 0.217 |
| W    | 19.81      | 21.08 | 0.780  | 0.830 |
| Z    | 2.50       | 2.70  | 0.098  | 0.106 |



## Rectifier

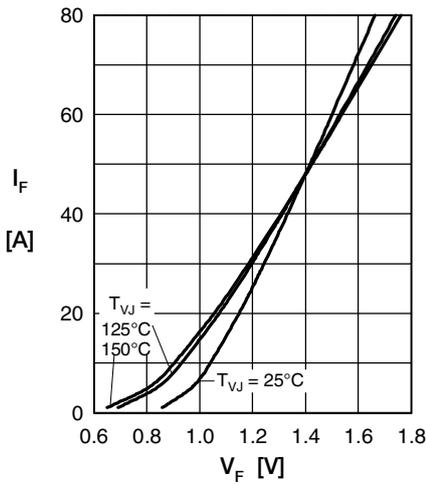


Fig. 1 Forward current vs. voltage drop per diode

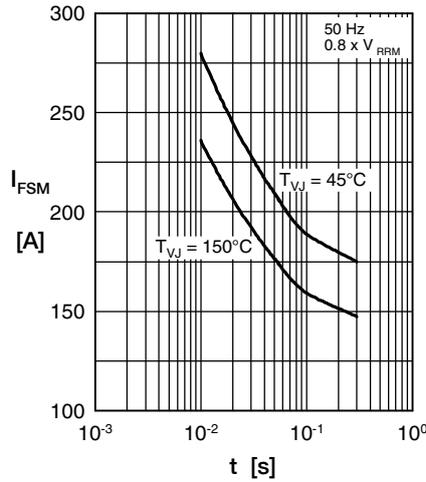


Fig. 2 Surge overload current vs. time per diode

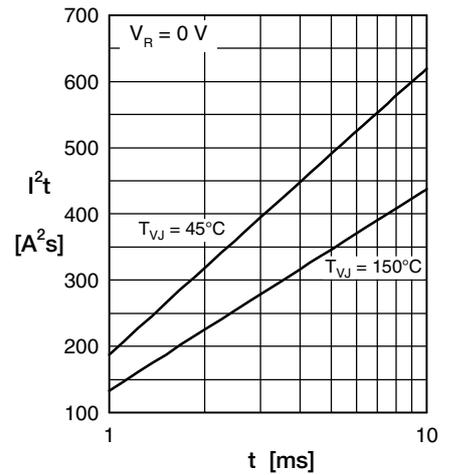


Fig. 3  $I^2t$  vs. time per diode

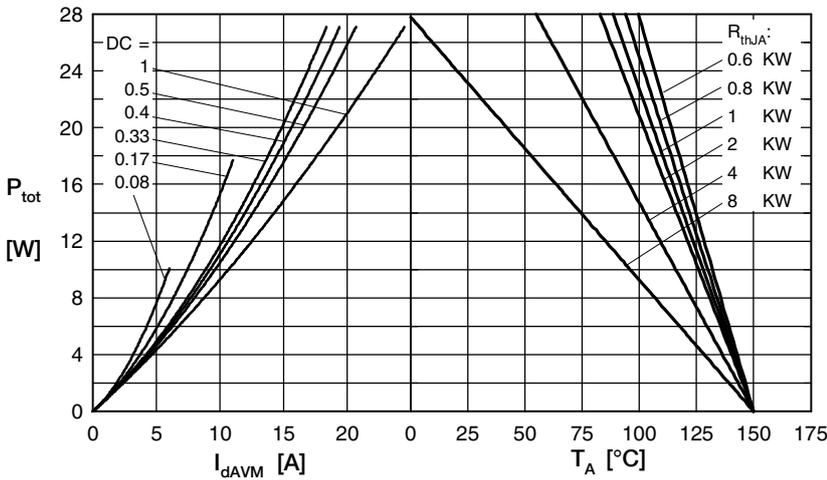


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

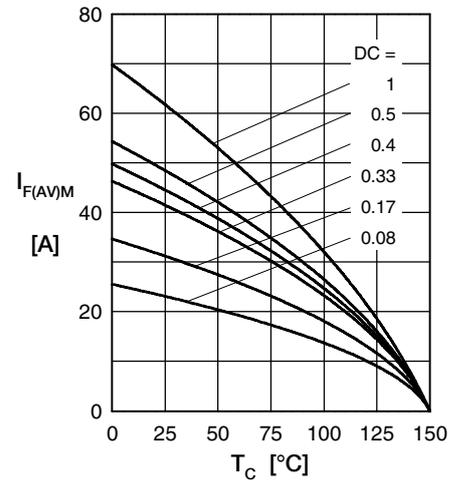


Fig. 5 Max. forward current vs. case temperature per diode

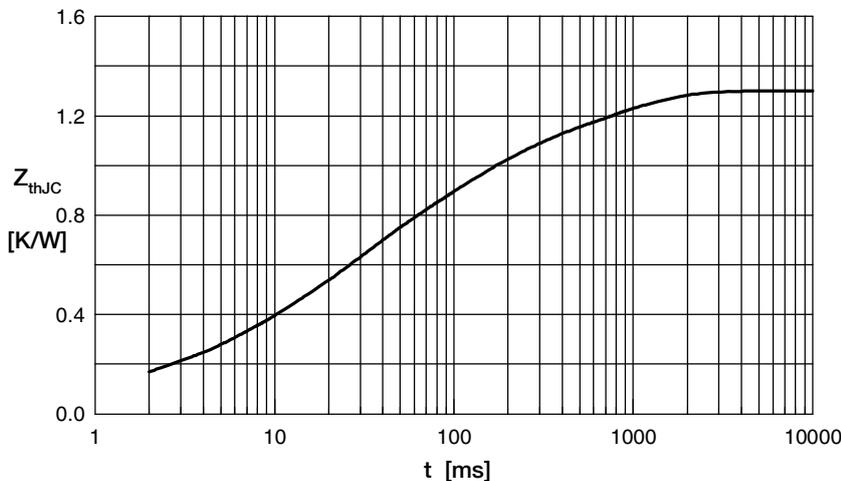


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

| i | $R_{th}$ (K/W) | $t_i$ (s) |
|---|----------------|-----------|
| 1 | 0.061          | 0.0002    |
| 2 | 0.145          | 0.0036    |
| 3 | 0.398          | 0.0200    |
| 4 | 0.405          | 0.1000    |
| 5 | 0.291          | 0.7000    |